	Application No.	Applicant(s)
A	10/773,902	NOMA, KENJI
Notice of Allowability	Examiner	Art Unit
	Tianjie Chen	2627
The MAILING DATE of this communication appearance All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIOF the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this ap or other appropriate communication IGHTS. This application is subject to	plication. If not included not included the mailed in due course. THIS
1. \boxtimes This communication is responsive to <u>Application filed on 0</u> :	<u>2/06/2004</u> .	
2. The allowed claim(s) is/are <u>1-12</u> .		
3. ☑ Acknowledgment is made of a claim for foreign priority ur a) ☑ All b) ☐ Some* c) ☐ None of the:	nder 35 U.S.C. § 119(a)-(d) or (f).	
1. ☐ Certified copies of the priority documents have been received.		
2. Certified copies of the priority documents have been received in Application No		
3. Copies of the certified copies of the priority documents have been received in this national stage application from the		
International Bureau (PCT Rule 17.2(a)).		
* Certified copies not received:		
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		complying with the requirements
4. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which give		
5. CORRECTED DRAWINGS (as "replacement sheets") must be submitted.		
(a) \square including changes required by the Notice of Draftspers	son's Patent Drawing Review (PTO	-948) attached
1) ☐ hereto or 2) ☐ to Paper No./Mail Date		
(b) ☐ including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or in the C	Office action of
Identifying indicia such as the application number (see 37 CFR 1 each sheet. Replacement sheet(s) should be labeled as such in t		
6. DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.		
Attachment(s)	E 🖂 Nation of Informacia	Octont Application (DTO 450)
 Notice of References Cited (PTO-892) D Notice of Draftperson's Patent Drawing Review (PTO-948) 	6. ☐ Interview Summary	Patent Application (PTO-152)
	Paper No./Mail Da	te
 Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 	08), 7. ⊠ Examiner's Amend	ment/Comment
4. Examiner's Comment Regarding Requirement for Deposit	8. X Examiner's Stateme	ent of Reasons for Allowance
of Biological Material	9. Other	
		Chan Longie
		TIANJIE CHEN PRIMARY EXAMINER

U.S. Patent and Trademark Office PTOL-37 (Rev. 7-05) Application/Control Number: 10/773,902

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EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

• In Specification, p. 5, line 2; "provide to" has been changed to --to provide--.

REASONS FOR ALLOWANCE

- 2. The following is an examiner's statement of reasons for allowance:
 - It is well known in the art that a large amount of magnetoresistance effect films have structure, which includes: a seed layer; a first pinned magnetic layer being formed on the seed layer; an antiferromagnetically coupling layer being formed on the first pinned magnetic layer; a second pinned magnetic layer being formed on the antiferromagnetically coupling layer; a nonmagnetic layer being formed on the second pinned magnetic layer; a free magnetic layer being formed on the nonmagnetic layer; and a protection layer being formed on the free magnetic layer. However, none of prior art on record further shows that the seed layer acts as a pinning layer, which fixes magnetizing directions of the first pinned magnetic layer and the second pinned magnetic layer, and the seed layer is made of a material which does not exchange-couple with the first pinned magnetic layer.
 - Applicant declares that the present invention is to provide a magnetoresistance
 effect film capable of performing enough function without employing an
 antiferromagnetic layer; thus having a narrow core width to realize high
 resolution (Specification, p.5).

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Conclusion

3. The prior art made of record in PTO-892 Form is considered pertinent to

applicant's disclosure.

Any comments considered necessary by applicant must be submitted no later

than the payment of the issue fee and, to avoid processing delays, should preferably

accompany the issue fee. Such submissions should be clearly labeled "Comments on

Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Tianjie Chen whose telephone number is 571-272-

7570. The examiner can normally be reached on 8:00-4:30, Mon-Fri.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Hoa Nguyen can be reached on 571-272-7579. The fax phone number for

the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the

Patent Application Information Retrieval (PAIR) system. Status information for

published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR

only. For more information about the PAIR system, see http://pair-direct.uspto.gov.

Should you have questions on access to the Private PAIR system, contact the

Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Chen Louryer
TIANJIE CHEN
PRIMARY EXAMINER